

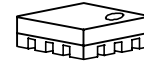
## PDC Dual Band MIXER GaAs MMIC

### ■GENERAL DESCRIPTION

The NJG1560PB1 is a mixer GaAs MMIC includes local amplifier targeted to dual band (800MHz, 1.5GHz) application. The band switching between 800MHz and 1500MHz is made by 1bit control signal by using inverter circuit included in this IC.

The ultra small and thin FFP12-B1 is applied.

### ■PACKAGE OUTLINE



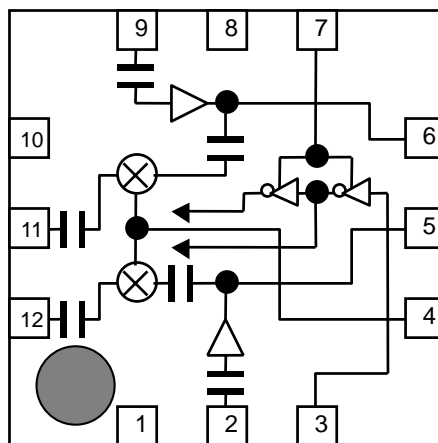
NJG1560PB1

### ■FEATURES

- |                             |   |  |
|-----------------------------|---|--|
| ●Low voltage operation      | +2.8V typ.                                  |  |
| ●Low current consumption    | 5.9mA typ.                                  |  |
| ●Low Inverter current       | 100uA typ.                                  |  |
| ●High conversion gain       | 11dB typ.                                   | @V <sub>CTL</sub> =0V, f <sub>RF1</sub> =820MHz    |
|                             | 11dB typ.                                   | @V <sub>CTL</sub> =2.4V, f <sub>RF2</sub> =1489MHz |
| ●High input IP3             | +3dBm typ.                                  | @V <sub>CTL</sub> =0V, f <sub>RF1</sub> =820MHz    |
|                             | +3dBm typ.                                  | @V <sub>CTL</sub> =2.4V, f <sub>RF2</sub> =1489MHz |
| ●Low noise figure           | 5.5dB typ.                                  | @V <sub>CTL</sub> =0V, f <sub>RF1</sub> =820MHz    |
|                             | 5.0dB typ.                                  | @V <sub>CTL</sub> =2.4V, f <sub>RF2</sub> =1489MHz |
| ●Ultra small & thin package | FFP12-B1 (Package size: 2.0mmx2.0mmx0.85mm) |  |

### ■PIN CONFIGURATION

(Top View)



Pin Connection

1. GND
2. LOIN1 (800MHz)
3. VCTL
4. IFOUT
5. VLO1 (800MHz)
6. VLO2 (1.5GHz)
7. VINV
8. GND
9. LOIN2 (1.5GHz)
10. GND
11. RFIN2 (1.5GHz)
12. RFIN1 (800MHz)

Note: The specifications and description listed in this catalog are subject to change without prior notice.

# NJG1560PB1

## ■ABSOLUTE MAXIMUM RATINGS

( $T_a=25^{\circ}\text{C}$ ,  $Z_s=Z_l=50\Omega$ )

| PARAMETERS            | SYMBOL    | CONDITIONS                       | RATINGS   | UNITS              |
|-----------------------|-----------|----------------------------------|-----------|--------------------|
| Operating voltage     | $V_{DD}$  | IFOUT, VLO 1, VLO2, VINV ports   | 5.0       | V                  |
| Control voltage       | $V_{CTL}$ | VCTL port                        | $V_{INV}$ | V                  |
| Input power           | $P_{in}$  | RFIN1, RFIN2, LOIN1, LOIN2 ports | +10       | dBm                |
| Power dissipation     | $P_D$     |                                  | 300       | mW                 |
| Operating temperature | $T_{opr}$ |                                  | -40~+85   | $^{\circ}\text{C}$ |
| Storage temperature   | $T_{stg}$ |                                  | -55~+125  | $^{\circ}\text{C}$ |

## ■ELECTRICAL CHARACTERISTICS 1 (DC)

GENERAL CONDITIONS:  $T_a=25^{\circ}\text{C}$ ,  $V_{MIX}=V_{LO1}=V_{LO2}=V_{INV}=2.8\text{V}$

| PARAMETERS                       | SYMBOL       | CONDITIONS   | MIN | TYP | MAX       | UNITS         |
|----------------------------------|--------------|--|-----|-----|-----------|---------------|
| Mixer supply voltage             | $V_{MIX}$    | IFOUT port   | 2.5 | 2.8 | 4.5       | V             |
| Local Amplifier supply voltage 1 | $V_{LO1}$    | VLO1 ports   | 2.5 | 2.8 | 4.5       | V             |
| Local Amplifier supply voltage 2 | $V_{LO2}$    | VLO2 ports   | 2.5 | 2.8 | 4.5       | V             |
| Inverter supply voltage          | $V_{INV}$    | VINV port  | 2.5 | 2.8 | 4.5       | V             |
| Mixer current                    | $I_{MIX}$    | IFOUT port, $P_{RF}=P_{LO}=\text{OFF}$ ,<br>$V_{CTL}=0\text{V}$ or $2.4\text{V}$ | -   | 4.9 | 6.1       | mA            |
| Local Amplifier current1         | $I_{LO1}$    | VLO1 port, $P_{RF}=P_{LO}=\text{OFF}$ ,<br>$V_{CTL}=0\text{V}$                   | -   | 1.0 | 1.2       | mA            |
| Local Amplifier current2         | $I_{LO2}$    | VLO2port, $P_{RF}=P_{LO}=\text{OFF}$ ,<br>$V_{CTL}=2.4\text{V}$                  | -   | 1.0 | 1.2       | mA            |
| Inverter current                 | $I_{INV}$    | VINV port  | -   | 100 | 150       | $\mu\text{A}$ |
| Control voltage (LOW)            | $V_{CTL(L)}$ | VCTL port  | 0   | 0   | 0.8       | V             |
| Control voltage (HIGH)           | $V_{CTL(H)}$ | VCTL port  | 2.0 | 2.4 | $V_{INV}$ | V             |
| Control current                  | $I_{CTL}$    | VCTL port, $V_{CTL}=2.4\text{V}$   | -   | 20  | 40        | $\mu\text{A}$ |

## ■ ELECTRICAL CHARACTERISTICS 2 (800MHz RF)

GENERAL CONDITIONS:  $T_a=+25^{\circ}\text{C}$ ,  $V_{\text{MIX}}=V_{\text{LO1}}=V_{\text{INV}}=2.8\text{V}$ ,  $V_{\text{CTL}}=0\text{V}$ ,  $f_{\text{RF1}}=820\text{MHz}$ ,  
 $P_{\text{RF1}}=-30\text{dBm}$ ,  $f_{\text{LO1}}=689.95\text{MHz}$ ,  $P_{\text{LO1}}=-15\text{dBm}$ ,  
 $f_{\text{IF}}=130.05\text{MHz}$ ,  $Z_s=Z_l=50\Omega$ , with application circuit

| PARAMETERS                         | SYMBOL                    | CONDITIONS                     | MIN   | TYP  | MAX  | UNITS |
|------------------------------------|---------------------------|--------------------------------|-------|------|------|-------|
| Operating frequency                | freq                      | RFIN1 port                     | 810   | 820  | 885  | MHz   |
| Conversion gain                    | Gc                        |                                | 10.0  | 11.0 | 12.0 | dB    |
| Noise figure                       | NF                        | SSB NF                         | -     | 5.5  | 6.5  | dB    |
| Input 3rd order intercept point    | IIP3                      | 2 tone offset frequency=100kHz | 0     | +3.0 | -    | dBm   |
| Pout at 1dB gain compression point | $P_{-1\text{dB(IN)}}$     |                                | -11.0 | -9.0 | -    | dBm   |
| RF IN1 port VSWR                   | $\text{VSWR}_{\text{RF}}$ |                                | -     | 1.5  | 2.0  |       |
| LOCAL IN1 port VSWR                | $\text{VSWR}_{\text{LO}}$ |                                | -     | 1.5  | 2.0  |       |
| IF OUT port VSWR                   | $\text{VSWR}_{\text{IF}}$ |                                | -     | 1.5  | 2.0  |       |

## ■ ELECTRICAL CHARACTERISTICS 3 (1.5GHz RF)

GENERAL CONDITIONS:  $T_a=+25^{\circ}\text{C}$ ,  $V_{\text{MIX}}=V_{\text{LO2}}=V_{\text{INV}}=2.8\text{V}$ ,  $V_{\text{CTL}}=2.4\text{V}$ ,  $f_{\text{RF2}}=1489\text{MHz}$ ,  
 $P_{\text{RF2}}=-30\text{dBm}$ ,  $f_{\text{LO2}}=1358.95\text{MHz}$ ,  $P_{\text{LO2}}=-15\text{dBm}$ ,  
 $f_{\text{IF}}=130.05\text{MHz}$ ,  $Z_s=Z_l=50\Omega$ , with application circuit

| PARAMETERS                         | SYMBOL                    | CONDITIONS                     | MIN   | TYP  | MAX  | UNITS |
|------------------------------------|---------------------------|--------------------------------|-------|------|------|-------|
| Operating frequency                | freq                      | RFIN2 port                     | 1477  | 1489 | 1501 | MHz   |
| Conversion gain                    | Gc                        |                                | 10.0  | 11.0 | 12.0 | dB    |
| Noise figure                       | NF                        | SSB NF                         | -     | 5.0  | 6.0  | dB    |
| Input 3rd order intercept point    | IIP3                      | 2 tone offset frequency=100kHz | 0     | +3.0 | -    | dBm   |
| Pout at 1dB gain compression point | $P_{-1\text{dB(IN)}}$     |                                | -11.0 | -9.0 | -    | dBm   |
| RF IN2 port VSWR                   | $\text{VSWR}_{\text{RF}}$ |                                | -     | 1.5  | 2.0  |       |
| LOCAL IN2 port VSWR                | $\text{VSWR}_{\text{LO}}$ |                                | -     | 1.5  | 2.0  |       |
| IF OUT port VSWR                   | $\text{VSWR}_{\text{IF}}$ |                                |       | 1.5  | 2.0  |       |

# NJG1560PB1

## ■TERMINAL INFORMATION

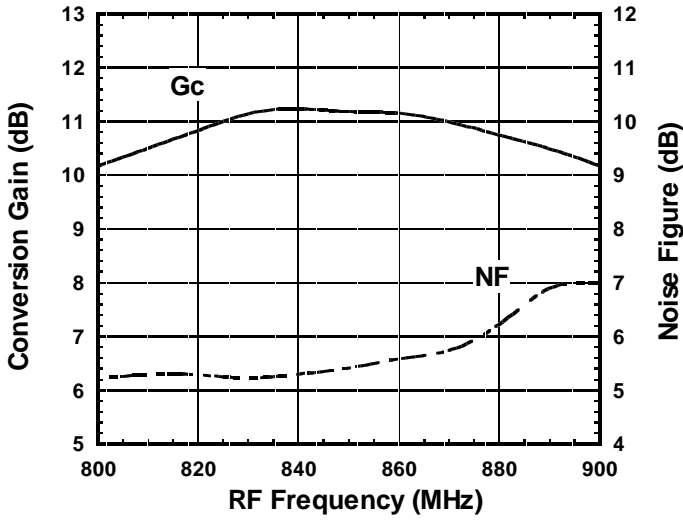
| Pin | Symbol | Description   |
|-----|--------|---|
| 1   | GND    | Ground terminal(0V).  |
| 2   | LOIN1  | Local power input terminal of 800MHz band local amplifier.<br>External matching circuit is required.  |
| 3   | VCTL   | Control voltage input terminal. This terminal is set to 800MHz band or 1.5GHz band to select.   |
| 4   | IFOUT  | IF signal output terminal for mixer external matching circuit is required.<br>Please connect mixer power supply through choke inductor (L7) as shown in test circuit. |
| 5   | VLO1   | 800MHz band local amplifier supply terminal.<br>Please place L6 close to this terminal as shown in test circuit.  |
| 6   | VLO2   | 1.5GHz band local amplifier supply terminal.<br>Please place L5 close to this terminal as shown in test circuit.  |
| 7   | VINV   | Power supply terminal of the inverter circuit.  |
| 8   | GND    | Ground terminal(0V).  |
| 9   | LOIN2  | Local power input terminal of 1.5GHz local amplifier.<br>External matching circuit is required.   |
| 10  | GND    | Ground terminal(0V).  |
| 11  | RFIN2  | RF input terminal of 1.5GHz band mixer.<br>External matching circuit is required.   |
| 12  | RFIN1  | RF input terminal of 800MHz band mixer.<br>External matching circuit is required.   |

NOTE:

- 1) Ground terminal (1, 8, 10pin) should be connected to ground plane by multiple via holes for good grounding.

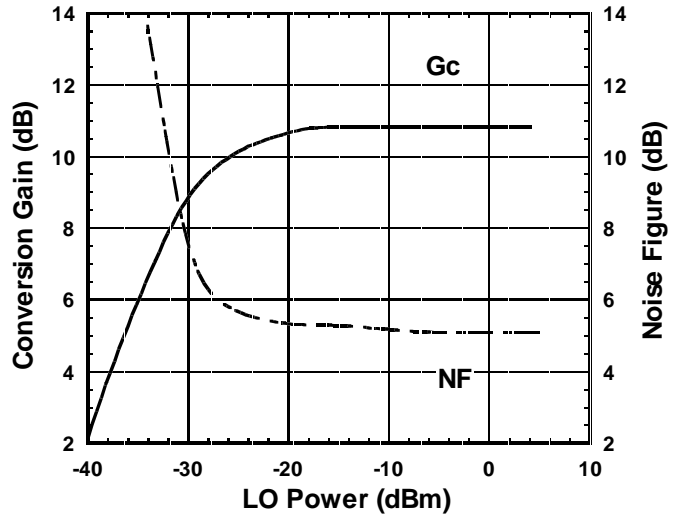
## ■ TYPICAL CHARACTERISTICS (800MHz Band)

### Gc , NF vs. RF Frequency



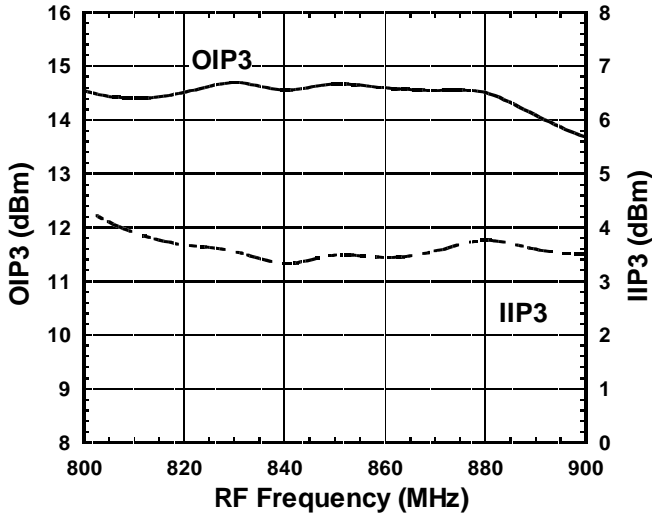
Condition  
 $f_{IF}=130.05\text{MHz}$   
 $f_{RF}=800\sim 900\text{MHz}$ ,  $P_{RF}=-30\text{dBm}$   
 $f_{LO}=669.95\sim 769.95\text{MHz}$ ,  $P_{LO}=-15\text{dBm}$   
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$   
 $V_{CTL}=0\text{V}$

### Gc, NF vs. LO Power



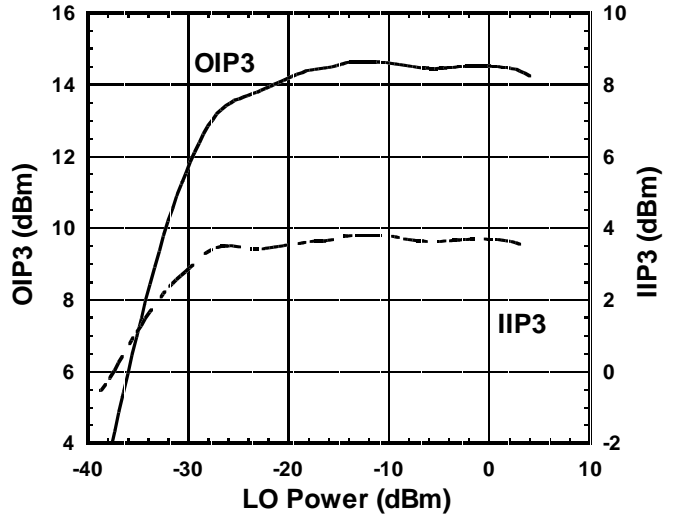
Condition  
 $f_{IF}=130.05\text{MHz}$   
 $f_{RF}=820\text{MHz}$ ,  $P_{RF}=-30\text{dBm}$   
 $f_{LO}=689.95\text{MHz}$   
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$   
 $V_{CTL}=0\text{V}$

### OIP3 , IIP3 vs. RF Frequency



Condition  
 $f_{IF}=130.05\text{MHz}$   
 $f_{RF1}=800\sim 900\text{MHz}$   
 $f_{RF2}=f_{RF1}+100\text{kHz}$ ,  $P_{RF}=-30\text{dBm}$   
 $f_{LO}=669.95\sim 769.95\text{MHz}$ ,  $P_{LO}=-15\text{dBm}$   
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$   
 $V_{CTL}=0\text{V}$

### OIP3, IIP3 vs. LO Power

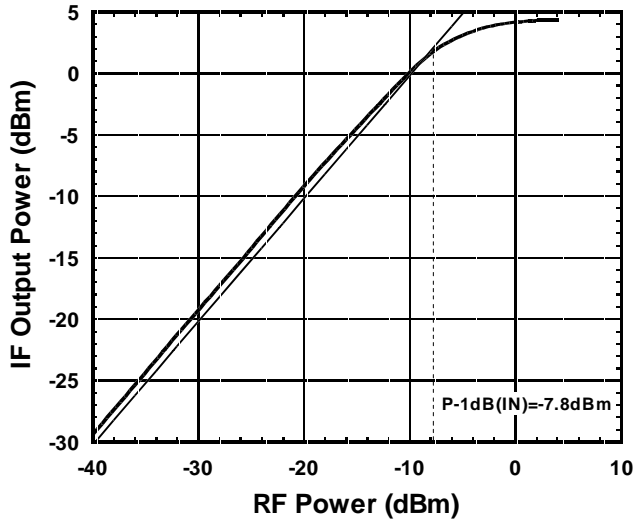


Condition  
 $f_{IF}=130.05\text{MHz}$   
 $f_{RF}=820.0+820.1\text{MHz}$ ,  
 $P_{RF}=-30\text{dBm}$   
 $f_{LO}=689.95\text{MHz}$   
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$   
 $V_{CTL}=0\text{V}$

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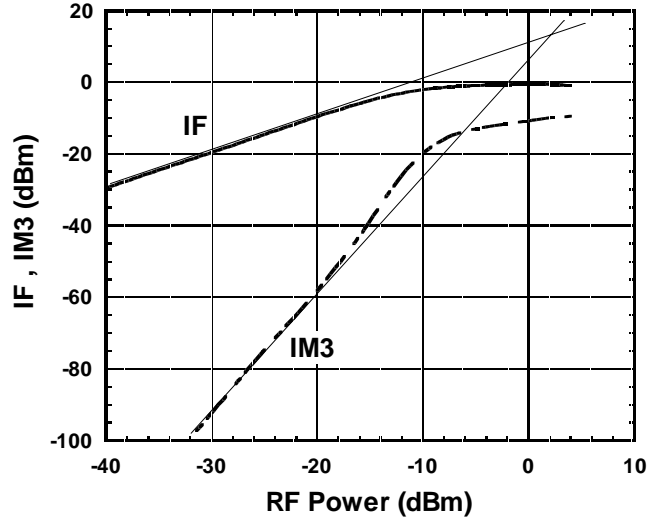
## TYPICAL CHARACTERISTICS (800MHz Band)

### IF Output Power vs. RF Power



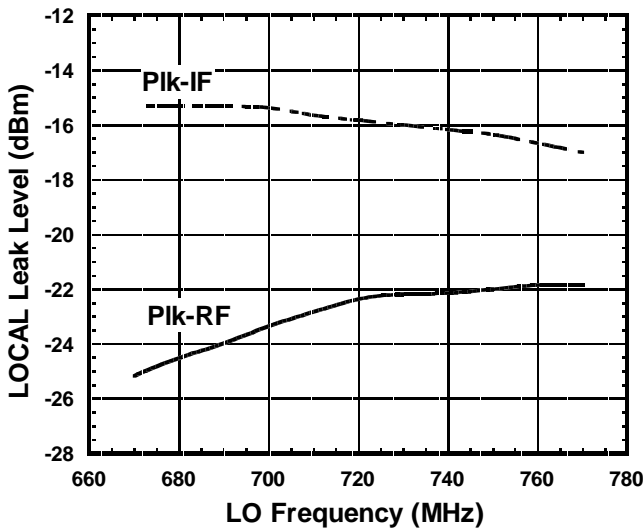
Condition  
 $f_{IF}=130.05\text{MHz}$   
 $f_{RF}=820\text{MHz}$   
 $f_{LO}=689.95\text{MHz}$ ,  $P_{LO}=-15\text{dBm}$   
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$   
 $V_{CTL}=0\text{V}$

### IF, IM3 vs. RF Power



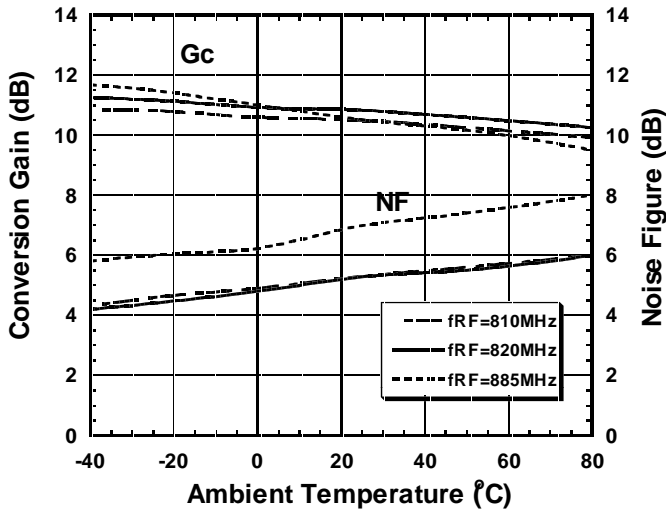
Condition  
 $f_{IF}=130.05\text{MHz}$   
 $f_{RF}=820.0+820.1\text{MHz}$   
 $f_{LO}=689.95\text{MHz}$ ,  $P_{LO}=-15\text{dBm}$   
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$   
 $V_{CTL}=0\text{V}$

### LOCAL Leak Level vs. LO Frequency



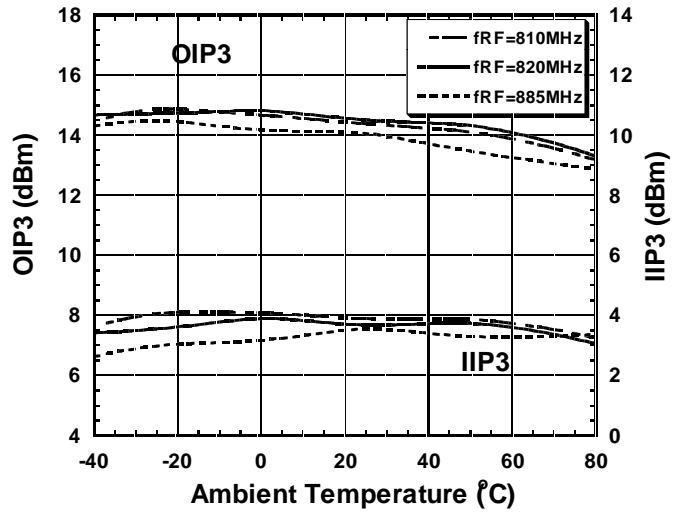
## ■ TYPICAL CHARACTERISTICS (800MHz Band)

### Gc, NF vs. Ambient Temperature



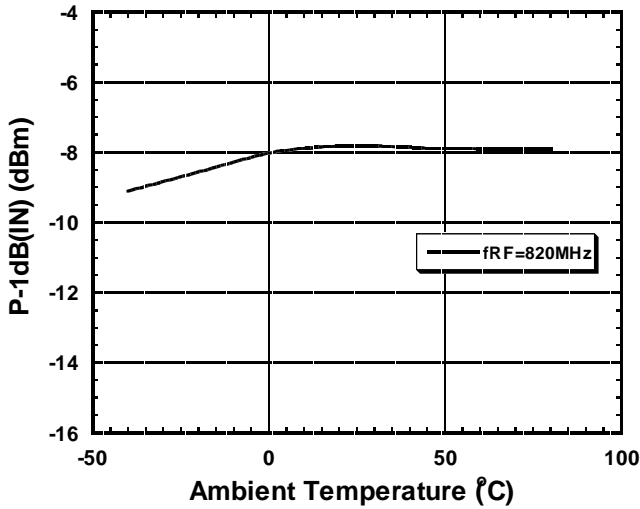
Condition  
 $f_{IF}=130.05\text{MHz}$   
 $f_{RF}=810\sim 885\text{MHz}$ ,  $P_{RF}=-30\text{dBm}$   
 $f_{LO}=679.95\sim 754.95\text{MHz}$ ,  $P_{LO}=-15\text{dBm}$   
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$   
 $V_{CTL}=0\text{V}$

### OIP3, IIP3 vs. Ambient Temperature



Condition  
 $f_{IF}=130.05\text{MHz}$   
 $f_{RF1}=810\sim 885\text{MHz}$ ,  
 $f_{RF2}=f_{RF1}+100\text{kHz}$ ,  $P_{RF}=-30\text{dBm}$   
 $f_{LO}=679.95\sim 754.95\text{MHz}$ ,  $P_{LO}=-15\text{dBm}$   
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$   
 $V_{CTL}=0\text{V}$

### P-1dB(IN) vs. Ambient Temperature

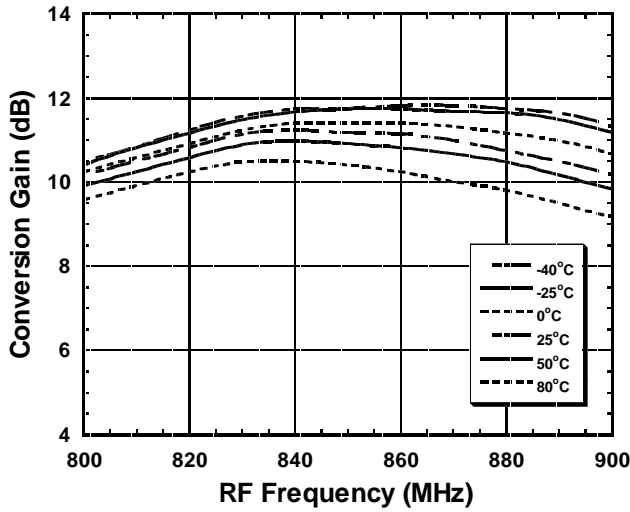


Condition  
 $f_{IF}=130.05\text{MHz}$   
 $f_{RF}=820\text{MHz}$   
 $f_{LO}=689.95\text{MHz}$ ,  $P_{LO}=-15\text{dBm}$   
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$   
 $V_{CTL}=0\text{V}$

# NJG1560PB1

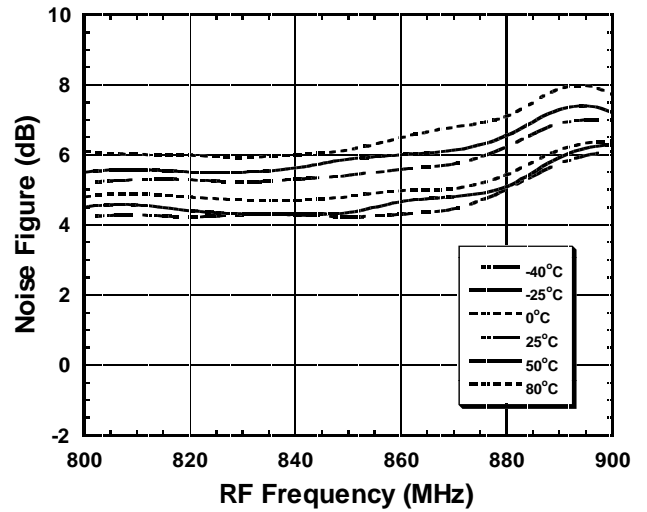
## TYPICAL CHARACTERISTICS (800MHz Band)

### Conversion Gain vs. Frequency



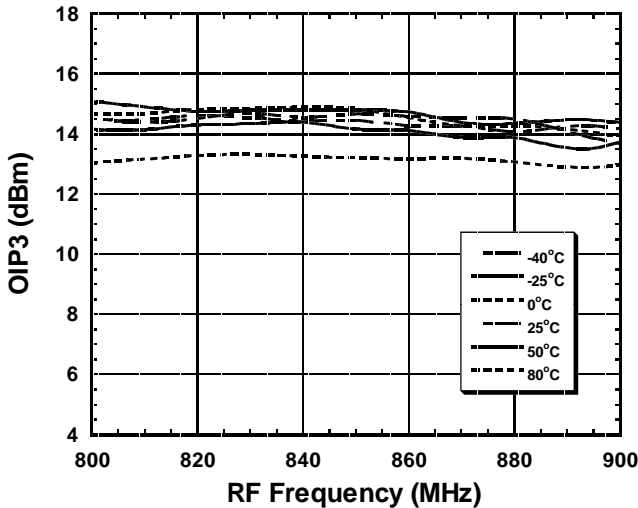
Condition  
 $f_{IF}=130.05\text{MHz}$   
 $f_{RF}=800\sim 900\text{MHz}$ ,  $P_{RF}=-30\text{dBm}$   
 $f_{LO}=669.95\sim 769.95\text{MHz}$ ,  $P_{LO}=-15\text{dBm}$   
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$   
 $V_{CTL}=0\text{V}$

### Noise Figure vs. Frequency



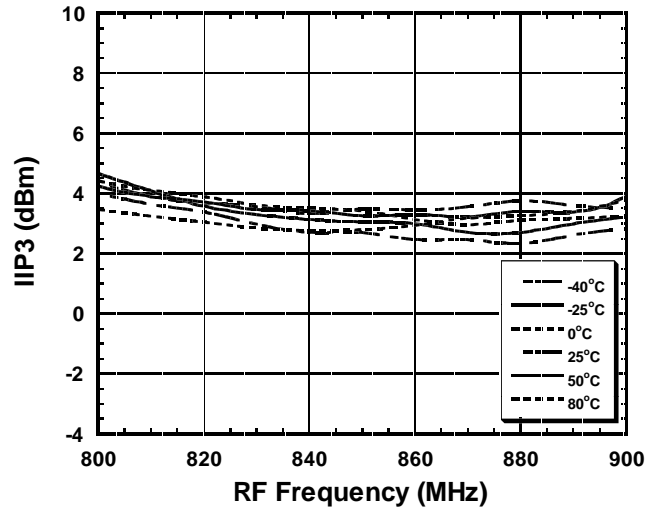
Condition  
 $f_{IF}=130.05\text{MHz}$   
 $f_{RF}=800\sim 900\text{MHz}$   
 $f_{LO}=669.95\sim 769.95\text{MHz}$ ,  $P_{LO}=-15\text{dBm}$   
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$   
 $V_{CTL}=0\text{V}$

### OIP3 vs. Frequency



Condition  
 $f_{IF}=130.05\text{MHz}$   
 $f_{RF1}=800\sim 900\text{MHz}$   
 $f_{RF2}=f_{RF1}+100\text{kHz}$ ,  $P_{RF}=-30\text{dBm}$   
 $f_{LO}=669.95\sim 769.95\text{MHz}$ ,  $P_{LO}=-15\text{dBm}$   
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$   
 $V_{CTL}=0\text{V}$

### IIP3 vs. Frequency

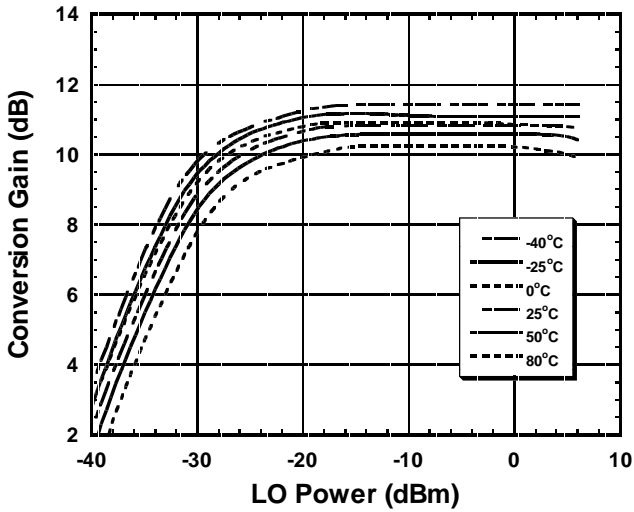


Condition  
 $f_{IF}=130.05\text{MHz}$   
 $f_{RF1}=800\sim 900\text{MHz}$   
 $f_{RF2}=f_{RF1}+100\text{kHz}$ ,  $P_{RF}=-30\text{dBm}$   
 $f_{LO}=669.95\sim 769.95\text{MHz}$ ,  $P_{LO}=-15\text{dBm}$   
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$   
 $V_{CTL}=0\text{V}$



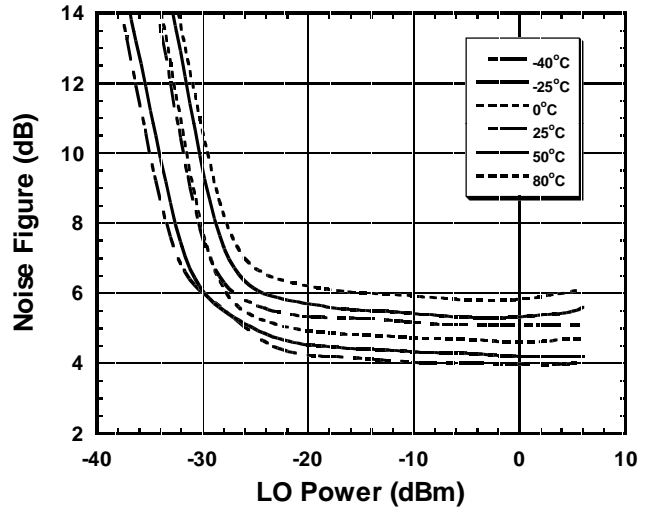
## TYPICAL CHARACTERISTICS (800MHz Band)

### Conversion Gain vs. LO Power



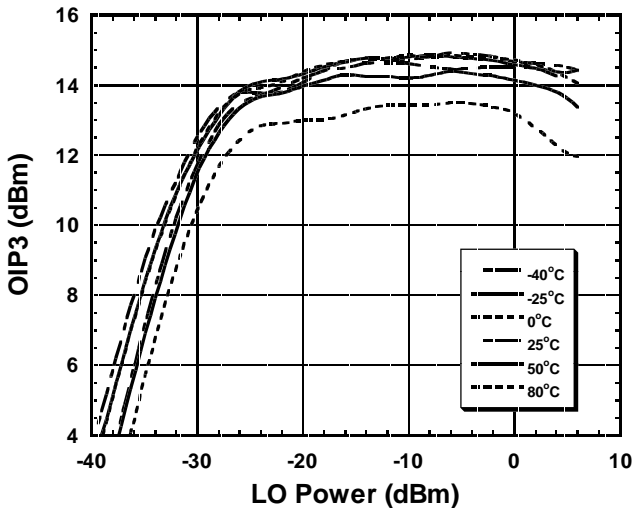
Condition  
 $f_{IF}=130.05\text{MHz}$   
 $f_{RF}=820\text{MHz}$ ,  $P_{RF}=-30\text{dBm}$   
 $f_{LO}=689.95\text{MHz}$   
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$   
 $V_{CTL}=0\text{V}$

### Noise Figure vs. LO Power



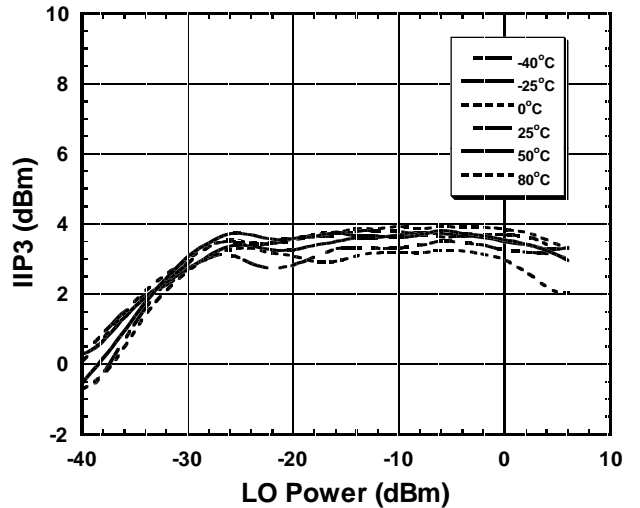
Condition  
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 $f_{RF}=820\text{MHz}$   
 $f_{LO}=689.95\text{MHz}$   
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$   
 $V_{CTL}=0\text{V}$

### OIP3 vs. LO Power



Condition  
 $f_{IF}=130.05\text{MHz}$   
 $f_{RF}=820.0+820.1\text{MHz}$ ,  
 $P_{RF}=-30\text{dBm}$   
 $f_{LO}=689.95\text{MHz}$   
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$   
 $V_{CTL}=0\text{V}$

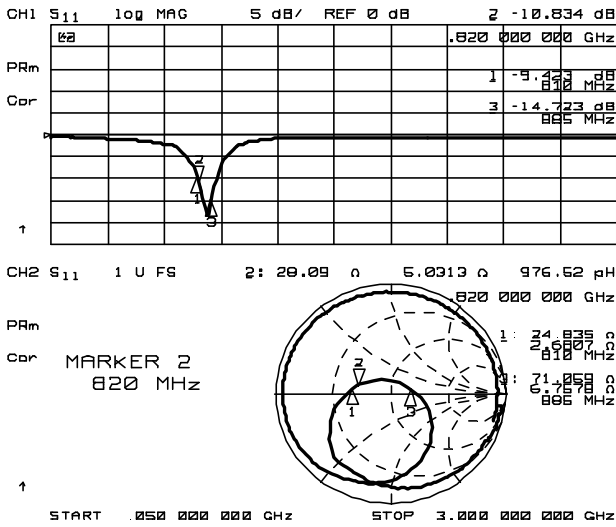
### IIP3 vs. LO Power



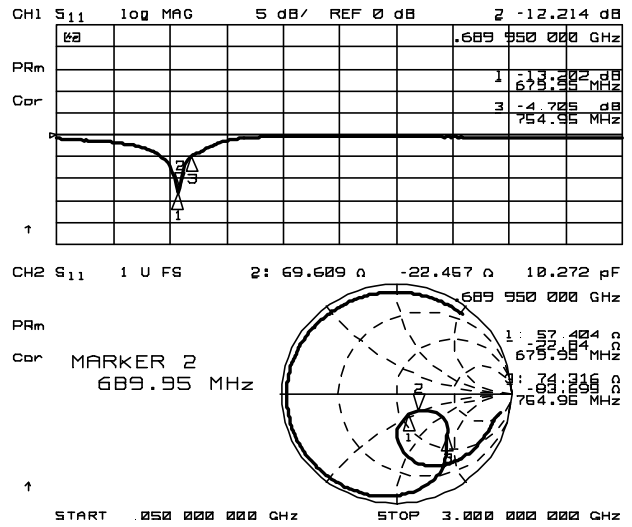
Condition  
 $f_{IF}=130.05\text{MHz}$   
 $f_{RF}=820.0+820.1\text{MHz}$ ,  
 $P_{RF}=-30\text{dBm}$   
 $f_{LO}=689.95\text{MHz}$   
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$   
 $V_{CTL}=0\text{V}$

# NJG1560PB1

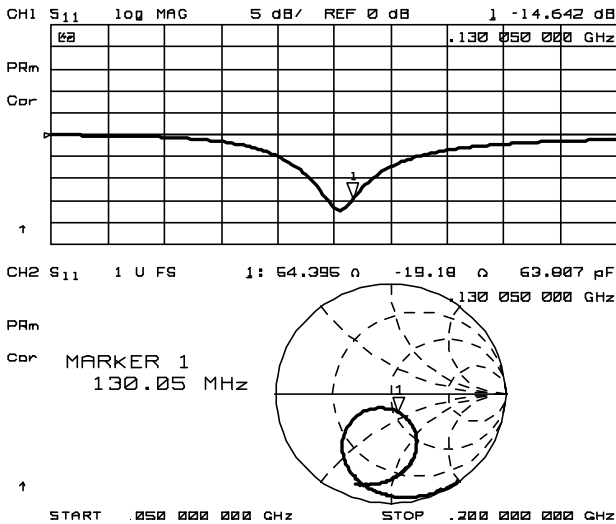
## TYPICAL CHARACTERISTICS (800MHz Band)



RF IN1 Port Impedance  
 (LOCAL IN1 Port, IF OUT Port: 50Ω term.)



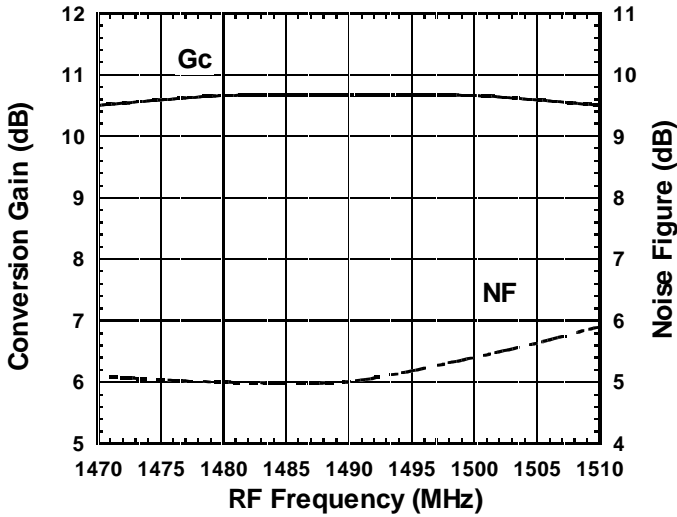
LOCAL IN1 Port Impedance  
 (RF IN1 Port, IF OUT Port: 50Ω term.)



IF OUT Port Impedance  
 (RF IN1 Port, LOCAL IN1 Port: 50Ω term.)

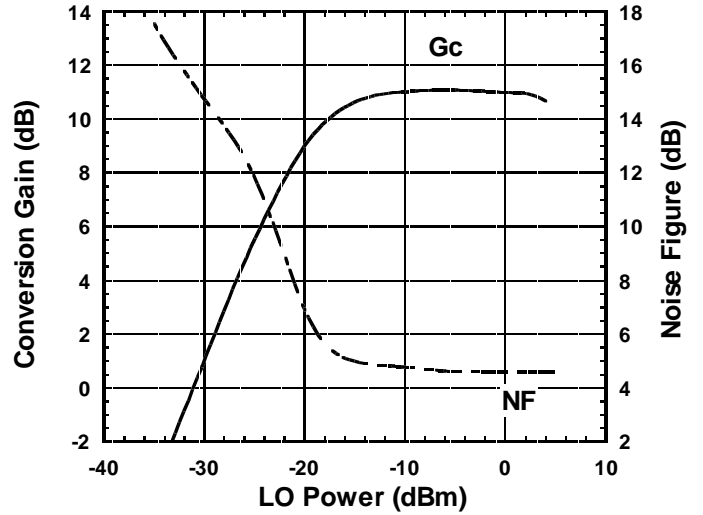
## ■ TYPICAL CHARACTERISTICS (1.5GHz Band)

### Gc , NF vs. RF Frequency



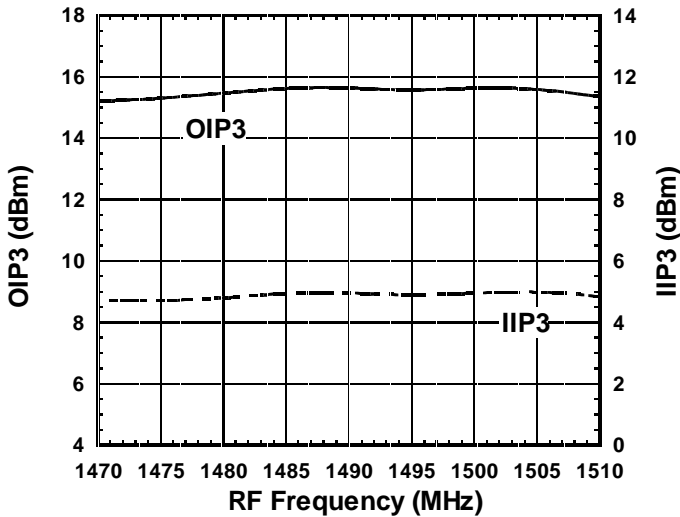
Condition  
 $f_{IF}=130.05\text{MHz}$   
 $f_{RF}=1470\sim 1510\text{MHz}$ ,  $P_{RF}=-30\text{dBm}$   
 $f_{LO}=1339.95\sim 1379.95\text{MHz}$ ,  $P_{LO}=-15\text{dBm}$   
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$   
 $V_{CTL}=2.4\text{V}$

### Gc , NF vs. LO Power



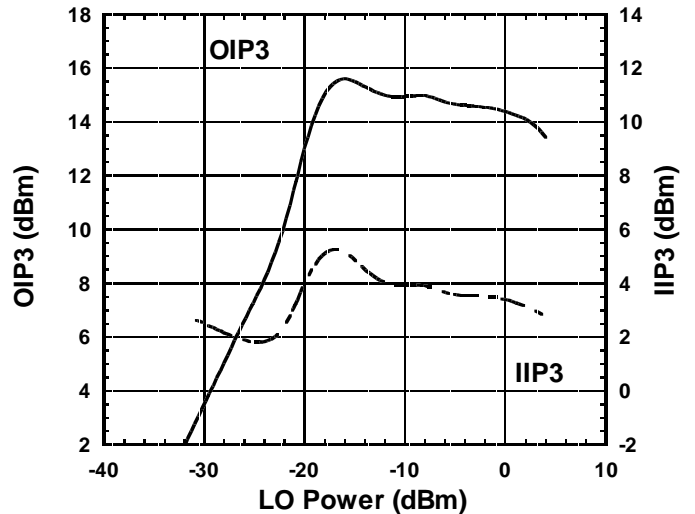
Condition  
 $f_{IF}=130.05\text{MHz}$   
 $f_{RF}=1489\text{MHz}$ ,  $P_{RF}=-30\text{dBm}$   
 $f_{LO}=1358.95\text{MHz}$   
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$   
 $V_{CTL}=2.4\text{V}$

### OIP3 , IIP3 vs. RF Frequency



Condition  
 $f_{IF}=130.05\text{MHz}$   
 $f_{RF1}=1470\sim 1510\text{MHz}$   
 $f_{RF2}=f_{RF1}+100\text{kHz}$ ,  $P_{RF}=-30\text{dBm}$   
 $f_{LO}=1339.95\sim 1379.95\text{MHz}$ ,  $P_{LO}=-15\text{dBm}$   
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$   
 $V_{CTL}=2.4\text{V}$

### OIP3 , IIP3 vs. LO Power

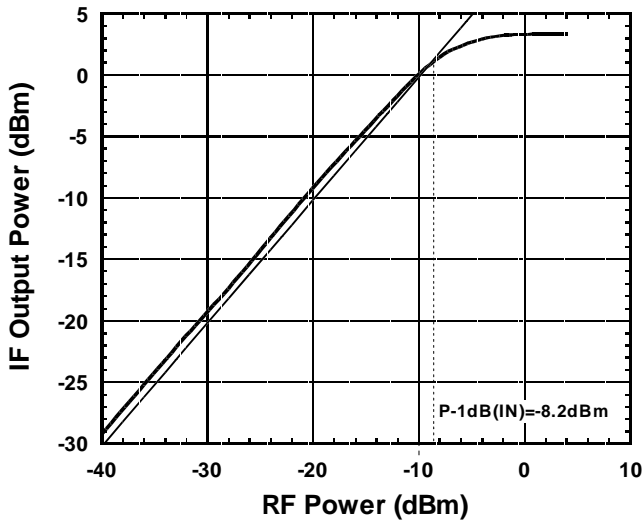


Condition  
 $f_{IF}=130.05\text{MHz}$   
 $f_{RF}=1489.0+1489.1\text{MHz}$ ,  $P_{RF}=-30\text{dBm}$   
 $f_{LO}=1358.95\text{MHz}$   
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$   
 $V_{CTL}=2.4\text{V}$

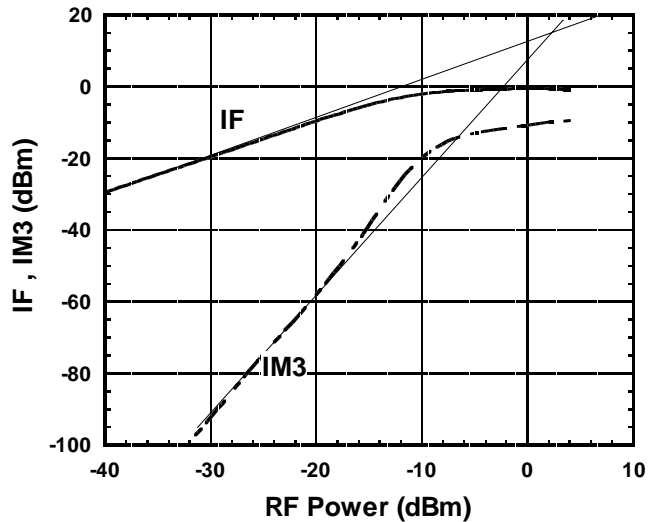
# NJG1560PB1

## TYPICAL CHARACTERISTICS (1.5GHz Band)

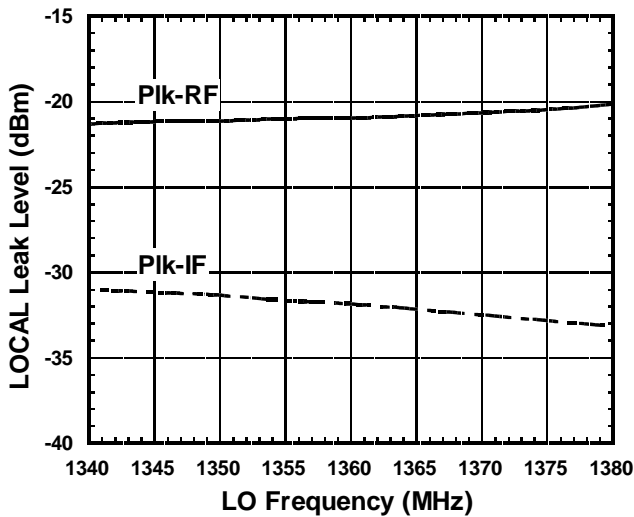
### IF Output Power vs. RF Power



### IF , IM3 vs. RF Power

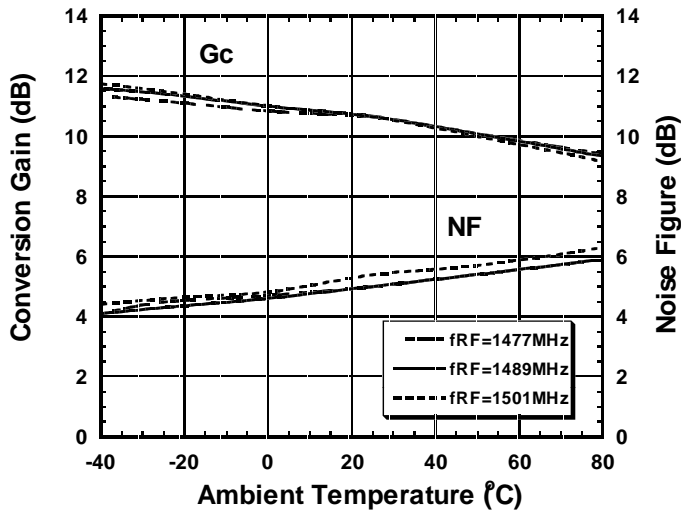


### LOCAL Leak Level vs. LO Frequency



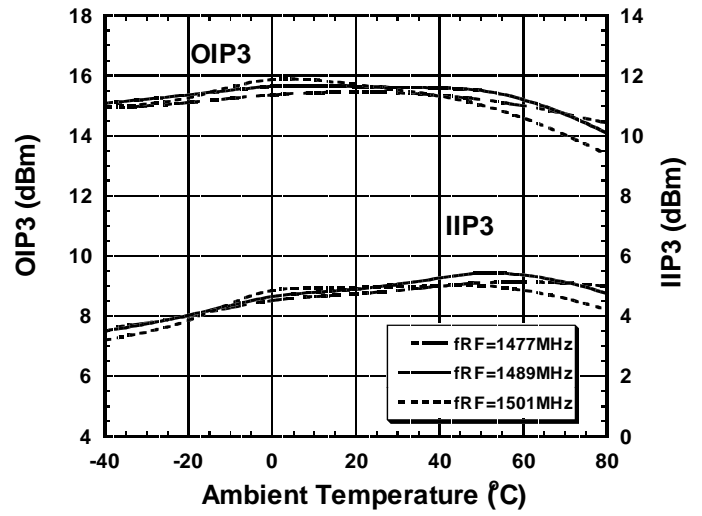
## ■ TYPICAL CHARACTERISTICS (1.5GHz Band)

### Gc, NF vs. Ambient Temperature



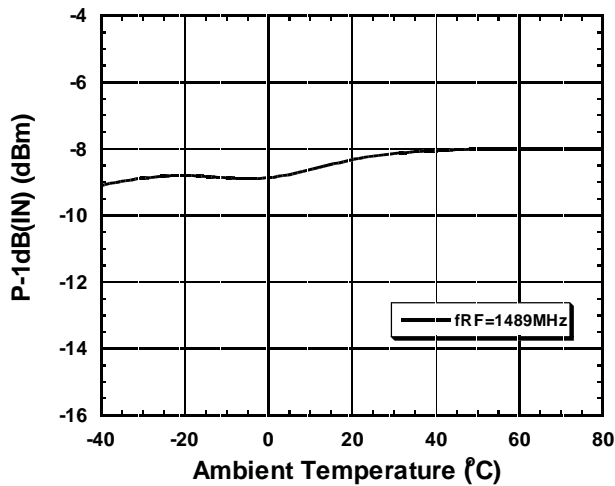
Condition  
 $f_{IF}=130.05\text{MHz}$   
 $f_{RF}=1477\sim 1501\text{MHz}$ ,  $P_{RF}=-30\text{dBm}$   
 $f_{LO}=1346.95\sim 1470.95\text{MHz}$ ,  $P_{LO}=-15\text{dBm}$   
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$   
 $V_{CTL}=2.4\text{V}$

### OIP3, IIP3 vs. Ambient Temperature



Condition  
 $f_{IF}=130.05\text{MHz}$   
 $f_{RF1}=1477\sim 1501\text{MHz}$ ,  
 $f_{RF2}=f_{RF1}+100\text{kHz}$ ,  $P_{RF}=-30\text{dBm}$   
 $f_{LO}=1346.95\sim 1470.95\text{MHz}$ ,  $P_{LO}=-15\text{dBm}$   
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$   
 $V_{CTL}=2.4\text{V}$

### P-1dB(IN) vs. Ambient Temperature

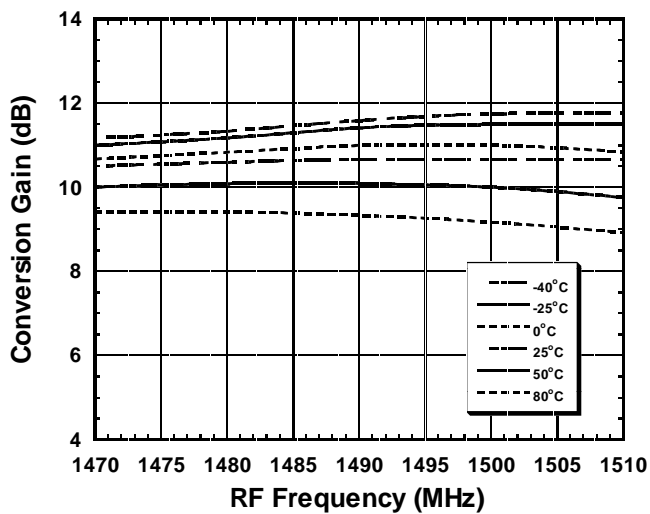


Condition  
 $f_{IF}=130.05\text{MHz}$   
 $f_{RF}=1489\text{MHz}$   
 $f_{LO}=1358.95\text{MHz}$ ,  $P_{LO}=-15\text{dBm}$   
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$   
 $V_{CTL}=2.4\text{V}$

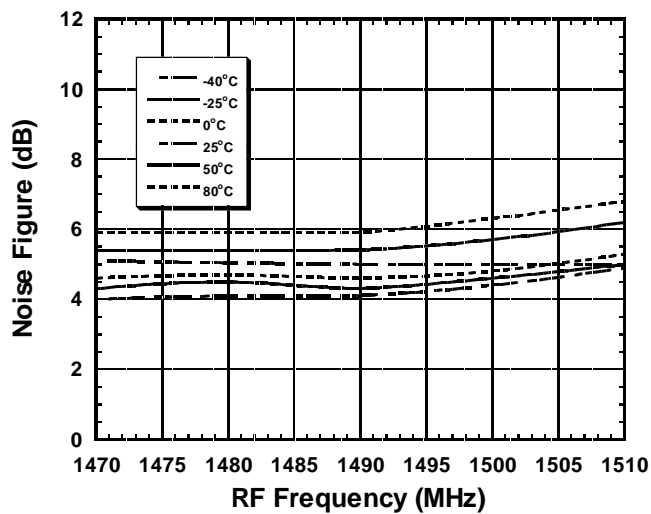
# NJG1560PB1

## TYPICAL CHARACTERISTICS (1.5GHz Band)

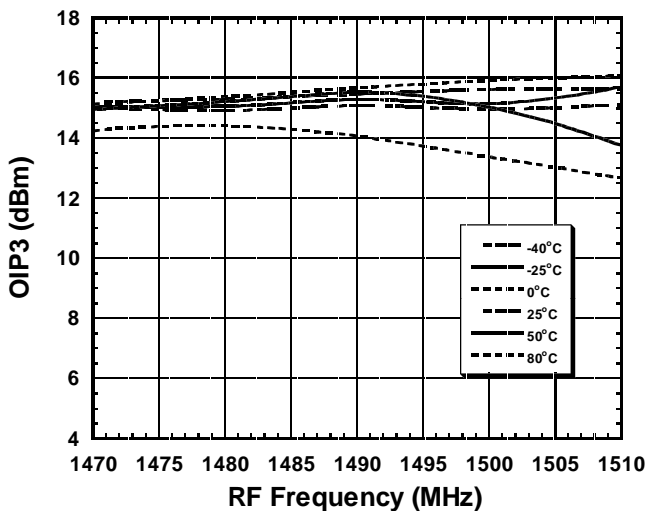
### Conversion Gain vs. Frequency



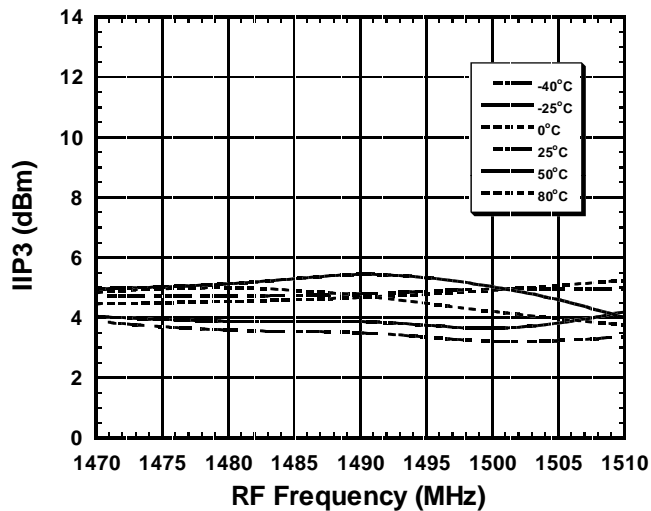
### Noise Figure vs. Frequency



### OIP3 vs. Frequency

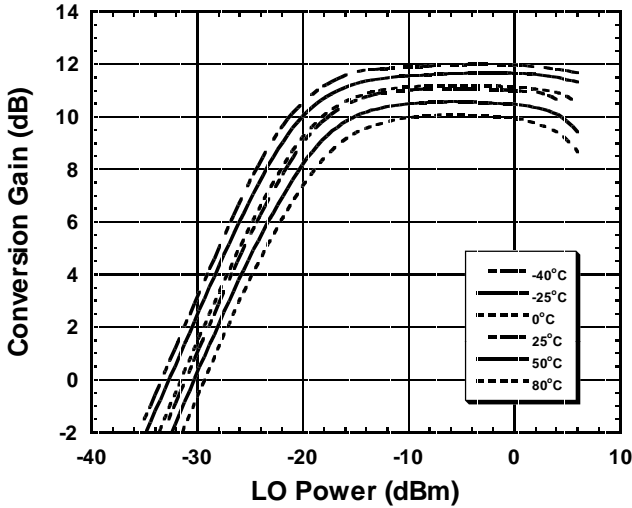


### IIP3 vs. Frequency



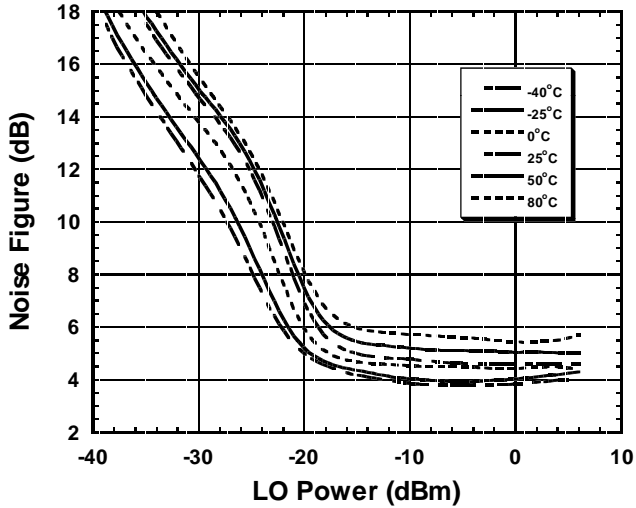
## TYPICAL CHARACTERISTICS (1.5GHz Band)

### Conversion Gain vs. LO Power



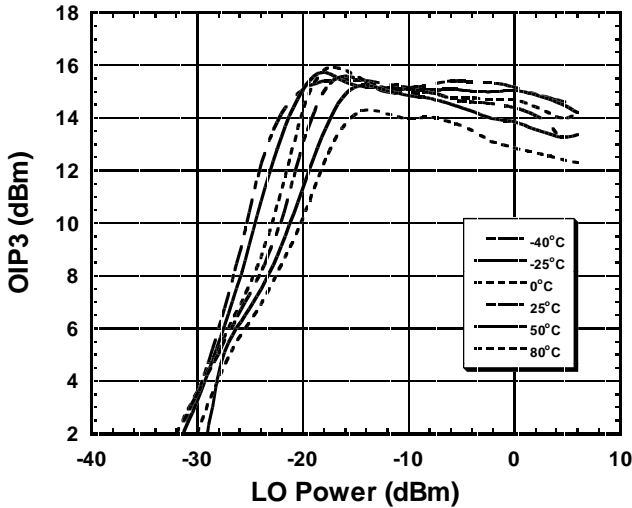
Condition  
 $f_{IF}=130.05\text{MHz}$   
 $f_{RF}=1489\text{MHz}$ ,  $P_{RF}=-30\text{dBm}$   
 $f_{LO}=1358.95\text{MHz}$   
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$   
 $V_{CTL}=2.4\text{V}$

### Noise Figure vs. LO Power



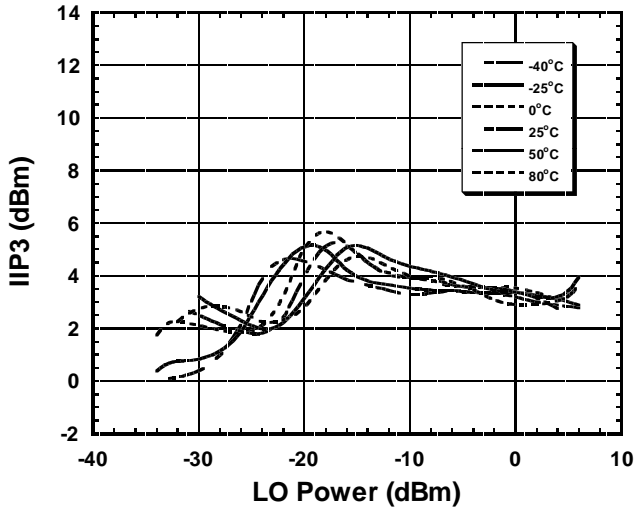
Condition  
 $f_{IF}=130.05\text{MHz}$   
 $f_{RF}=1489\text{MHz}$   
 $f_{LO}=1358.95\text{MHz}$   
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$   
 $V_{CTL}=2.4\text{V}$

### OIP3 vs. LO Power



Condition  
 $f_{IF}=130.05\text{MHz}$   
 $f_{RF}=1489.0+1489.1\text{MHz}$ ,  $P_{RF}=-30\text{dBm}$   
 $f_{LO}=1358.95\text{MHz}$   
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$   
 $V_{CTL}=2.4\text{V}$

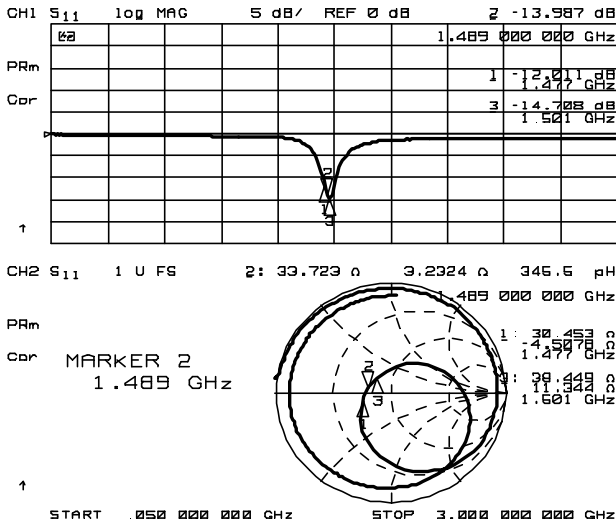
### IIP3 vs. LO Power



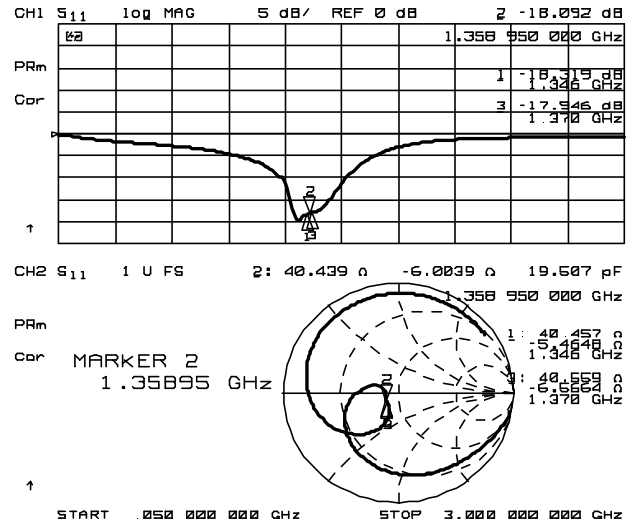
Condition  
 $f_{IF}=130.05\text{MHz}$   
 $f_{RF}=1489.0+1489.1\text{MHz}$ ,  $P_{RF}=-30\text{dBm}$   
 $f_{LO}=1358.95\text{MHz}$   
 $V_{MIX}=V_{LO}=V_{INV}=2.8\text{V}$   
 $V_{CTL}=2.4\text{V}$

# NJG1560PB1

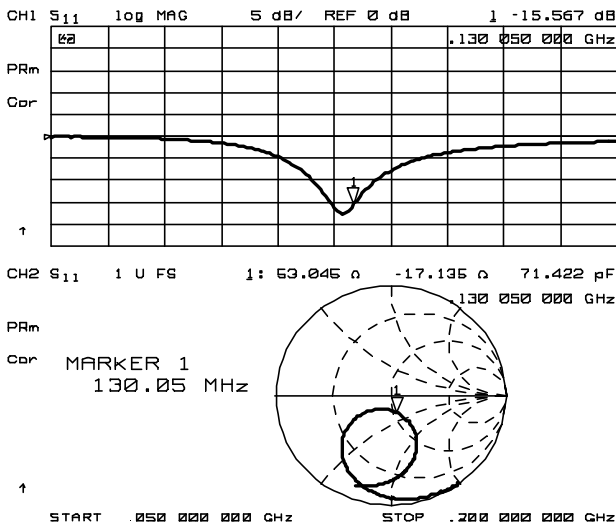
## TYPICAL CHARACTERISTICS (1.5GHz Band)



RF IN2 Port Impedance  
(LOCAL IN2 Port, IF OUT Port: 50 $\Omega$  term.)



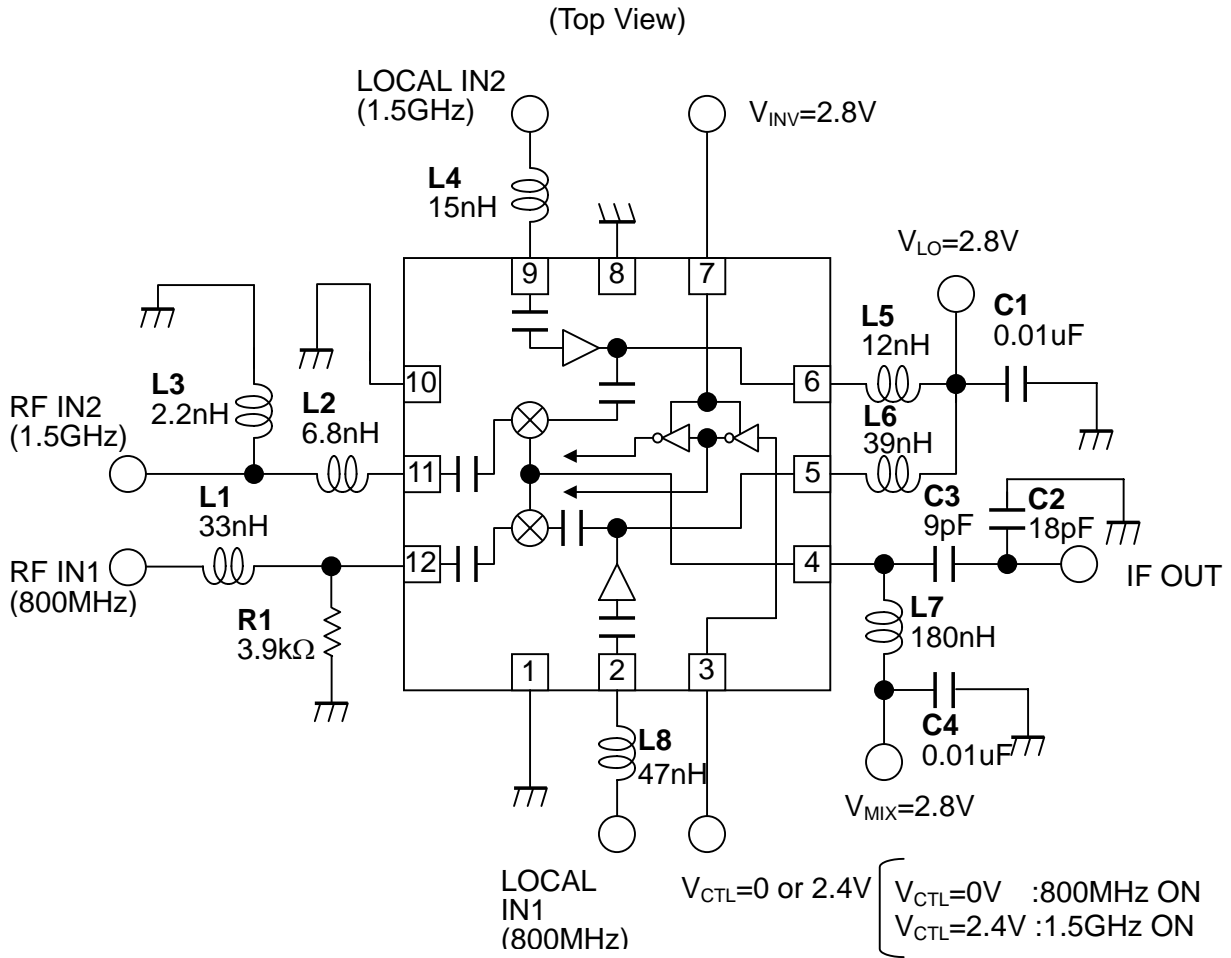
LOCAL IN2 Port Impedance  
(RF IN2 Port, IF OUT Port: 50 $\Omega$  term.)



IF OUT Port Impedance  
(RF IN2 Port, LOCAL IN2 Port: 50 $\Omega$  term.)



## APPLICATION CIRCUIT

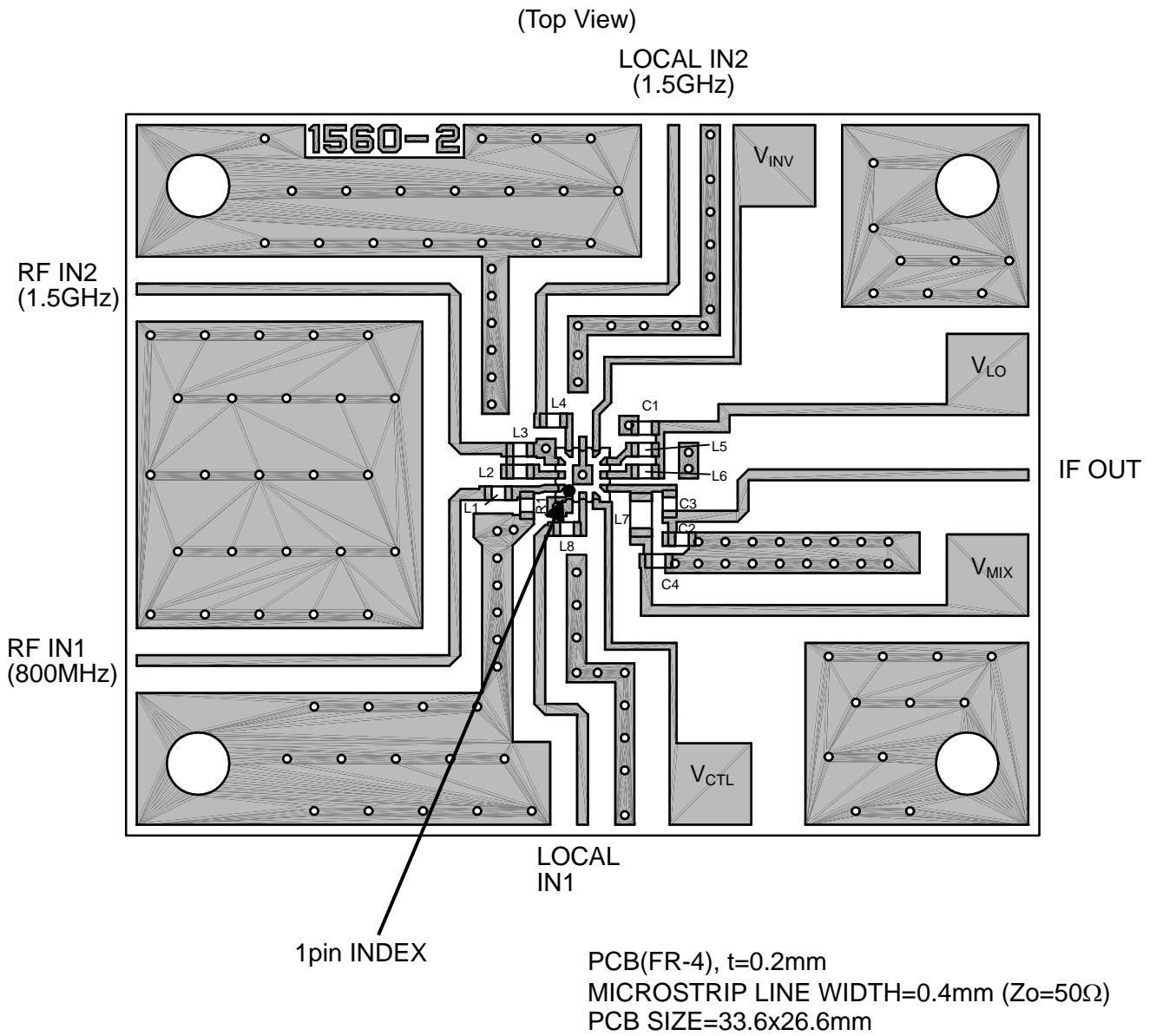


### Parts list

| PARTS ID | COMMENT                        |
|----------|--------------------------------|
| L1       | TAIYO-YUDEN (HK1005, 1005size) |
| L2       | TAIYO-YUDEN (HK1005, 1005size) |
| L3       | TAIYO-YUDEN (HK1005, 1005size) |
| L4       | TAIYO-YUDEN (HK1005, 1005size) |
| L5       | TAIYO-YUDEN (HK1005, 1005size) |
| L6       | TAIYO-YUDEN (HK1005, 1005size) |
| L7       | TAIYO-YUDEN (HK1608, 1608size) |
| L8       | TAIYO-YUDEN (HK1005, 1005size) |
| C1       | MURATA (GRM36, 1005size)       |
| C2       | MURATA (GRM36, 1005size)       |
| C3       | MURATA (GRM36, 1005size)       |
| C4       | MURATA (GRM36, 1005size)       |
| R1       | 1005 Size                      |

# NJG1560PB1

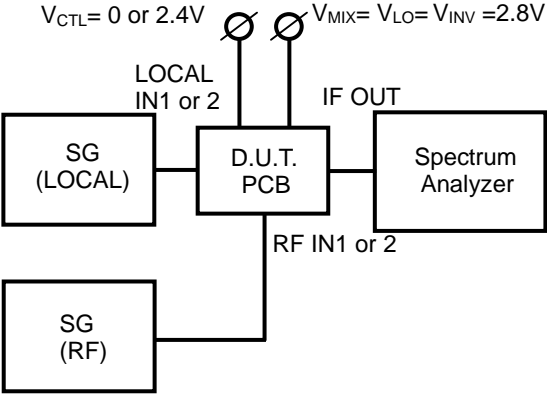
## RECOMMENDED PCB DESIGN



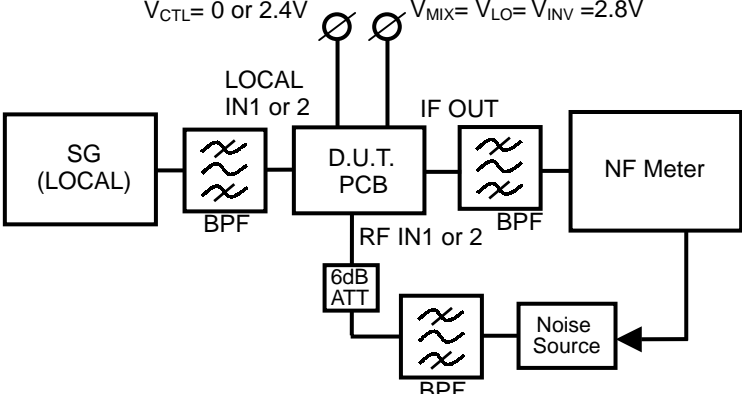
### PRECAUTIONS

1. Please locate L6 close to VLO1 terminal (5).
2. Please locate L5 close to VLO2 terminal (6).
3. Please locate C1 close to L5 and L6.
4. Please locate C4 close to L7.

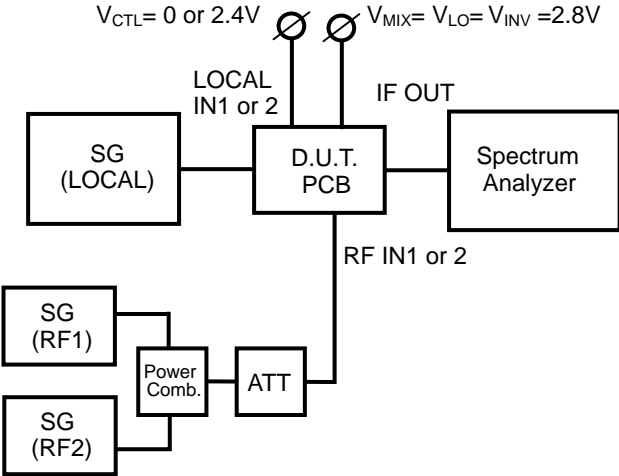
MEASURING BLOCK DIAGRAM



Conversion Gain Measuring Block Diagram



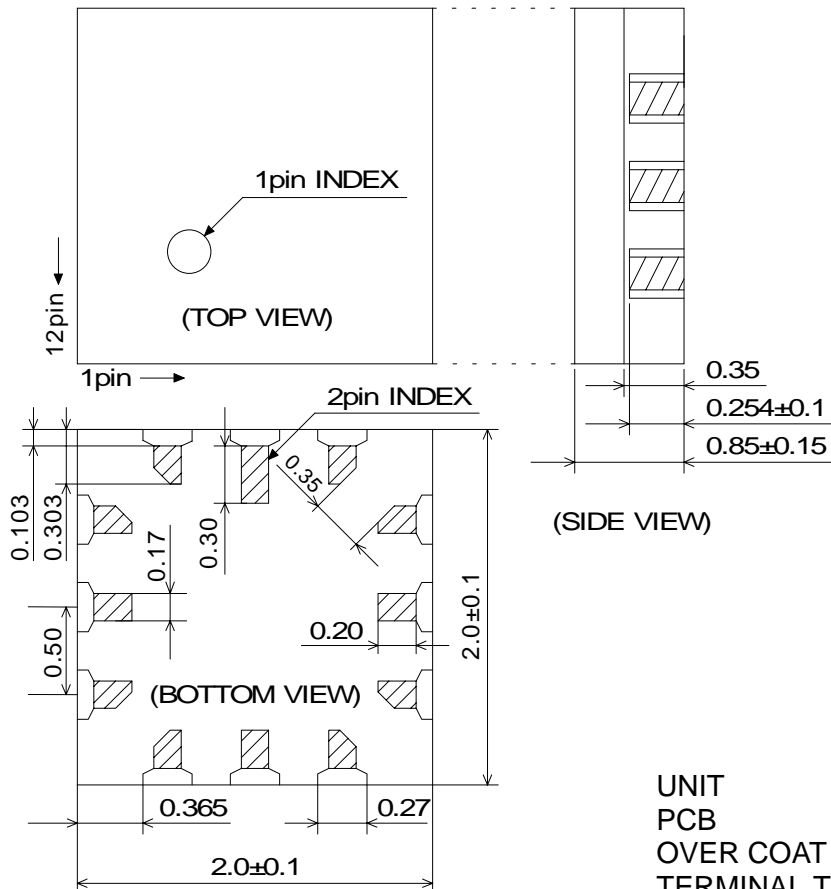
Noise Figure Measuring Block Diagram



OIP3, IIP3 Measuring Block Diagram

# NJG1560PB1

## PACKAGE OUTLINE (FFP12-B1)



UNIT : mm  
 PCB : Ceramic  
 OVER COAT : Epoxy resin  
 TERMINAL TREAT : Au  
 WEIGHT : 10mg

### Cautions on using this product

- This product contains Gallium-Arsenide (GaAs) which is a harmful material.
- Do NOT eat or put into mouth.
  - Do NOT dispose in fire or break up this product.
  - Do NOT chemically make gas or powder with this product.
  - To waste this product, please obey the relating law of your country.

### [CAUTION]

The specifications on this databook are only given for information, without any guarantee as regards either mistakes or omissions. The application circuits in this databook are described only to show representative usages of the product and not intended for the guarantee or permission of any right including the industrial rights.

This product may be damaged with electric static discharge (ESD) or spike voltage. Please handle with care to avoid these damages.

# Mouser Electronics

Authorized Distributor

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- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
- Сертификаты соответствия на поставляемую продукцию (по желанию клиента).
- Тестирование поставляемой продукции.
- Поставку компонентов, требующих военную и космическую приемку.
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- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



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Email: [org@lifeelectronics.ru](mailto:org@lifeelectronics.ru)